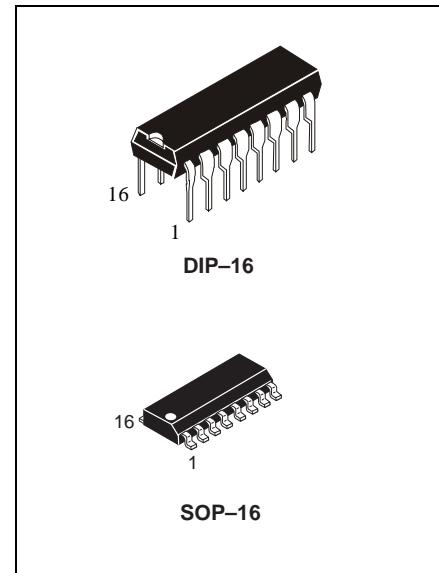


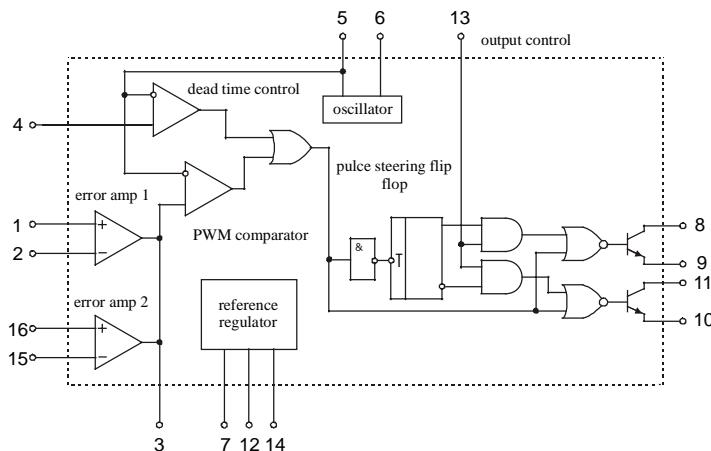
SWITCHMODE Pulse Width Modulation Control Circuit

The TL494 is a fixed frequency, pulse width modulation control circuit designed primarily for SWITCHMODE power supply control.

- Complete Pulse Width Modulation Control Circuitry
- On-Chip Oscillator with Master or Slave Operation
- On-Chip Error Amplifiers
- On-Chip 5.0 V Reference
- Adjustable Deadtime Control
- Uncommitted Output Transistors Rated to 500 mA Source or Sink
- Output Control for Push-Pull or Single-Ended Operation
- Undervoltage Lockout



LOGIC DIAGRAM



Pin 7 = GND
Pin 12 = V_{cc}

PIN ASSIGNMENT

noninv. input	1	U	16	noninv. input
inv. input	2	15	inv. input	
feedback	3	14	ref. output	
dead time control	4	TL494	output control	
C _T	5	12	V _{cc}	
R _T	6	11	collector 2	
gnd	7	10	emitter 2	
collector 1	8	9	emitter 1	

MAXIMUM AND RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Recommended operating conditions		Maximum ratings		Unit
		Min	Max	Min	Max	
V _{CC}	Supply Voltage	7	40		41	V
V _I	Amplifier Input Voltage	-0.3	V _{CC} -2		V _{CC} +0.3	V
V _O	Collector Output Voltage		40		41	V
I _{OC}	Collector Output Current (Each Transistor)		200		250	mA
T	Storage Temperature Range			-65	150	°C
T	Operating Free-Air Temperature Range	-20	85			°C

ELECTRICAL CHARACTERISTICS (T_A= -20 ...+85°C, f =10kHz)

Symbol	Parameter	Test Conditions	Value		Tempe- rature, ° C	Unit
			Min	Max		
V _{ref}	Output voltage	I ₀ =1.0mA V _{CC} =15V	4.75	5.25	-20...+85	V
U _{regin}	Input regulation	V _{CC} =7... 40V I ₀ =1.0mA	-	25	25	mV
U _{regout}	Output regulation	I ₀ =1... 10 mA V _{CC} =15V	-	15	25	mV
ΔV _{ref}	Output voltage change with temperature	I ₀ =1mA V _{CC} =15V	-	1.0	-20...+85	%
I _{SC}	Short circuit output current	V _{ref} =0 tsc< 1s V _{CC} =15 V	-	50		mA
f _{osc}	Frequency	C=0.01μF, R=12kΩ V _{CC} =15V V ₍₀₃₎ =0.7V	6.0	14		kHz
σf _{osc}	Standard Deviation of Frequency *	V _{CC} =15V V ₍₀₃₎ =0.7V	-	15		%
σf _{osc(ΔV)}	Frequency Change with Voltage	V _{CC} =7...40 V V ₍₀₃₎ =0.7V	-	10	25	%
σf _{osc(ΔT)}	Frequency Change with Temperature	C=0.01μF, R _T =12kΩ V _{CC} =15V V ₍₀₃₎ =0.7V	-	2.0	-20...+85	%
I _{IB(2T)}	Input bias current (pin 4)	V _I =0...5.25V V _{CC} =15V V ₍₀₃₎ =0.7V	-	-10		μA
DCmax	Maximum duty cycle (each output)	V _{I(04)} =0V V _{CC} =15V V ₍₀₃₎ =0.7V	45	-		%
V _{THD1}	Input threshold voltage (pin 4) (Zero Duty Cycle)	DCmax=0 V _{CC} =15V V ₍₀₃₎ =0.7V	-	3,3		V

V _{THD2}	Input threshold voltage (pin 4) (Maximum Duty Cycle)	Dcmax V _{CC} =15V V ₍₀₃₎ =0.7V	0	-		V
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Symbol	Parameter	Test Conditions	Value		Tempe- rature, °C	Unit
			Min	Max		
t _{rc}	Output voltage rise time (Common-Emitter)	V _{CC} =15V V ₍₀₃₎ =2.0V	-	200	-20...+85	ns
t _{fc}	Output voltage fall time (Common-Emitter)	V _{CC} =15V V ₍₀₃₎ =2.0V	-	100		ns
t _{rf}	Output voltage rise time (Emitter-Follower)	V _{CC} =V _C =15V V ₍₀₃₎ =2.0V	-	200		ns
t _{ff}	Output voltage fall time (Emitter-Follower)	V _{CC} =V _C =15V V ₍₀₃₎ =2.0V	-	100		ns
V _{THP}	Input threshold voltage (pin 3)	DCmax=0 V _{CC} =15V	-	4.5		V
I _I	Input sink current (pin 3)	V _{CC} =15V V ₍₀₃₎ =0.7V	0.3	-		mA
V _{IO}	Input offset voltage	V _{CC} =15V V _{O(03)} =2.5V	-	10		mV
I _{IO}	Input offset current	V _{CC} =15V V _{O(03)} =2.5V	-	250		nA
I _{IB}	Input bias current	V _{CC} =15V V _{O(03)} =2.5V	-	1		μA
V _{ICRL}	Low Input common mode voltage range	V _{CC} =7...40V	-0.3	-		V
V _{ICRH}	High Input common mode voltage range	V _{CC} =7...40V	V _{CC} -2	-		V
A _{VOL}	Open loop voltage amplification	ΔV ₀ =3V V _{CC} =15V V _O =0.5...3.5V	70	-	-20...+85	dB
f _b	Unity-gain bandwidth	V _{CC} =15V	100	-		kHz
CMRR	Common mode rejection ratio	V _{CC} =40V	65	-		dB
I _{OL}	Output sink current (pin 3)	V _{CC} =15V V _{O(03)} =0.7V	0.3	-		mA
I _{OH}	Output source current (pin 3)	V _{CC} =15V V _{O(03)} =3.5V	-2.0	-		mA
I _{C(off)}	Collector off-state current	V _{CE} =V _{CC} =40V	-	100		μA

I _{E(off)}	Emitter off-state current	V _{CC} =V _C =40V V _E =0V	-	-100		µA
V _{SAT(C)}	Collector - Emitter saturation voltage (Common-Emitter)	V _{CC} =15V V _E =0V V ₀₍₀₃₎ =3.0V I _C =200mA	-	1.3		V
V _{SAT(E)}	Collector - Emitter saturation voltage (Emitter-follower)	V _{CC} =V _C =15V I _E =-200mA V ₀₍₀₃₎ =3.0V	-	2.5	25	V
				2.9	-20...+85	
I _{OCH}	Output control input current	V _{CC} =15V V ₀₍₀₃₎ =0.7V	-	3.5	25	mA
I _{CC15}	Standby Supply Current at V _{CC} 15V	V _{CC} =15V	-	10		mA

Symbol	Parameter	Test Conditions	Value		Tempe- rature, °C	Unit
			Min	Max		
I _{CC40}	Standby Supply Current at V _{CC} 40V	V _{CC} =40V	-	15	25	mA
I _{CCA}	Average Supply Current	V _{CC} =15V V ₀₍₀₃₎ =0.7V V ₀₍₀₄₎ =2.0V	-	17	-20...+85	mA

Standard deviation is a measure of the statistical distribution about the mean as derived from the formula

$$\sigma = \sqrt{\frac{\sum_{n=1}^N (X_n - \bar{X})^2}{N - 1}}$$

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